## Systematic pseudopotentials from reference eigenvalue sets for DFT calculations Additional information

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Keywords: A. Pseudopotentials, B. Numerical atomic orbitals, C. Density-functional theory.

We display in the following pages those elements for which we are unable to improve the electronic dispersion in a significant manner: C, Al, Si, V, Cr, Cu, Se, Nb, and Te. Please refer to Table 2 in the main text to assess the overall improvement by means of the ratio  $Y_o/Y_i$ .

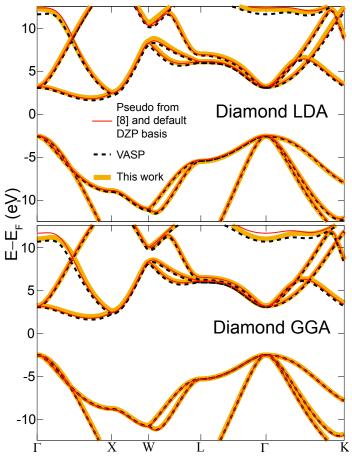


Figure 1: C(Z = 6)

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